

HALOGEN

FREE



High Voltage 4 Ω Quad SPST CMOS Analog Switch

DESCRIPTION

The DG454 series has four independently selectable high voltage (44 V) SPST switches, each with a typical on resistance of 4 Ω and a typical flatness of 0.2 Ω , ideal parameters for low distortion audio signal switching.

The DG454 (NC) and DG455 (NO) are identical except for the digital logic control input, which is inverted as shown in the Truth Table. The DG456 has two normally closed and two normally open switches.

These are high voltage switches that are fully specified with dual supplies at \pm 5 V and \pm 15 V and a single supply of 12 V.

Fast switching speeds coupled with high signal bandwidth makes these parts suitable for video switching applications.

All digital inputs have 0.8 V and 2.4 V logic thresholds ensuring low voltage TTL/CMOS compatibility. Each switch conducts equally well in both directions when on and can handle an input signal range that extends to the supply voltage rails.

The DG454 DG455 and DG456 are pin compatible with the DG411, DG412 and DG413, except they require no V_L supply.

FEATURES

- Low on-resistance (4 Ω typical)
- On-resistance flatness (0.2 Ω typical)
- · 100 mA continuous current
- 44 V supply maximum rating
- ± 15 V analog signal range
- Fully specified at supply voltages of ± 5 V, 12 V and ± 15 V
- No V_L required
- · Fast switching speed:
 - t_{on} 80 ns
 - t_{off} 60 ns
- TTL/CMOS compatible
- ESD protection 2 kV
- Pin compatible with DG411, DG412, and DG413, except no V_I required
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

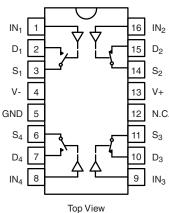
- · Audio and video signal switching
- · Precision automatic test equipment
- · Precision data acquisition
- · Relay replacement
- Communications systems
- Automotive and avionics applications
- Sample and hold systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG454 TSSOP16 and SOIC16 IN_2 IN₁ D_2 D₁ S_1 V-GND N C S_4 S_3 D_4 D_3 IN_4 IN_3 Top View

TRUTH TABLE								
Logic DG454 DG455								
0	On	Off						
1	Off	On						

DG456 TSSOP16 and SOIC16



TRUTH TABL	E	
Logic	SW ₁ , SW ₄	SW ₂ , SW ₃
0	Off	On
1	On	Off

DG454, DG455, DG456

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ORDERING INFORMATION								
Temp. Range	np. Range Package Part Number							
DG454, DG455, DG456								
40.00 to 405.008	16 Pin TSSOP	DG454EQ-T1-E3 DG455EQ-T1-E3 DG456EQ-T1-E3						
- 40 °C to 125 °C ^a	16 Pin Narrow SOIC	DG454EY-T1-E3 DG455EY-T1-E3 DG456EY-T1-E3						

Notes:

a. - 40 °C to 85 °C datasheet limits apply.

Parameter		Limit	Unit	
V+ to V-		44		
GND to V-		25	V	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first]	
Continuous Current (D, S only)		100	mA	
Peak Current, S or D (Pulsed 1 ms, 10 %	6 Duty Cycle)	300	IIIA	
Storage Temperature		- 65 to 150	°C	
Daniel Disciplina (Daniel Daniel	16 Pin TSSOP ^c	450	mW	
Power Dissipation (Package) ^b	16 Pin Narrow SOIC ^d	600		
Ti 15 :: (5 !)b	16 Pin TSSOP	178	°C/W	
Thermal Resistance (Package) ^D	16 Pin Narrow SOIC	125	J -C/VV	
ESD (HBM)	<u>.</u>	2	kV	

Notes:

- $a. \ Signals \ on \ S_X, \ D_X, \ or \ IN_X \ exceeding \ V+ \ or \ V- \ will \ be \ clamped \ by \ internal \ diodes. \ Limit forward \ diode \ current \ to \ maximum \ current \ ratings.$
- b. All leads welded or soldered to PC board.
- c. Derate 5.6 mW/°C above 70 °C.
- d. Derate 8 mW/°C above 75 °C.

SPECIFICATIONS	SPECIFICATIONS FOR DUAL SUPPLIES									
_	Cumahal	Test Conditions Unless Specified	- h		- 40 °C t	o 125 °C	- 40 °C	to 85 °C	1114	
Parameter	Symbol	V+ = 15 V, V- = - 15 V V _{IN} = 2.4 V, 0.8 V ^a	Temp.b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit	
Analog Switch					•					
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V	
On-Resistance	R _{ON}	$I_S = -10 \text{ mA}, V_D = -10 \text{ V to} + 10 \text{ V}$	Room Full	3.8		5.3 8.3		5.3 7.3		
On-Resistance Match	ΔR _{ON}	$I_S = -10 \text{ mA}, V_D = \pm 10 \text{ V}$	Room Full	0.12		0.5 1		0.5 0.5	Ω	
On-Resistance Flatness	R _{FLATNESS}	I _S = - 10 mA, V _D = - 5 V, 0 V, + 5 V	Room Full	0.25		0.5 0.5		0.5 0.5		
Switch Off	I _{S(off)}	$V_D = \pm 10 \text{ V}, V_S = 10 \text{ V}$	Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5		
Leakage Current	I _{D(off)}	V _D = ± 10 V, V _S = 10 V	Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5	nA	
Channel On Leakage Current	I _{D(on)}	$V_S = V_D = \pm 10 \text{ V}$	Room Full	± 0.1	- 1 - 40	1 40	- 1 - 5	1 5		





		Test Conditions Unless Specified	_ h		- 40 °C to 125 °C		- 40 °C to 85 °C		
Parameter	Symbol	V ₊ = 15 V, V ₋ = - 15 V V _{IN} = 2.4 V, 0.8 V ^a		Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit
Digital Control									
Input Current, V _{IN} Low	I _{IL}	V _{IN} Under Test = 0.8 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	
Input Current, V _{IN} High	I _{IH}	V _{IN} Under Test = 2.4 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μΑ
Input Capacitance ^e	C _{IN}	f = 1 MHz	Room	7					pF
Dynamic Characteristics					•				
Turn-On Time	t _{ON}	$R_L = 300 \Omega$, $C_L = 35 pF$	Room Full	88		118 160		118 144	
Turn-Off Time	t _{OFF}	$V_S = \pm 10 \text{ V}$, See Figure 2	Room Full	69		97 120		97 112	ns
Break-Before-Make Time Delay	t _D	DG456 only, $V_S = 10 \text{ V}$ $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$	Room	18					
Charge Injection ^e	Q	$V_g = 0 \text{ V, } R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	22					рC
Off Isolation ^e	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF$	Room	- 60					
Channel-to-Channel Crosstalk ^e	X _{TALK}	f = 1 MHz	Room	- 85					dB
Source Off Capacitance ^e	C _{S(off)}		Room	31					
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz	Room	34					pF
Channel On Capacitance ^e	C _{D(on)}		Room	103					μ.
Total Harmonic Distortion ^e	THD	Signal = 5 V_{RMS} , 20 Hz to 20 kHz, $R_L = 600 \Omega$	Room	0.04					%
Power Supplies					1	l		l	
Power Supply Current	l+		Room Full	25		100 100		100 100	
Negative Supply Current	l-	V+ = 16.5 V, V- = - 16.5 V V _{IN} = 0 or 5 V	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ
Ground Current	I_{GND}		Room Full	- 25	- 100 - 100		- 100 - 100		

SPECIFICATIONS FOR DUAL SUPPLIES									
_	Test Conditions Unless Specified		_ h		- 40 °C t	o 125 °C	- 40 °C to 85 °C		Unit
Parameter	Symbol	V+ = 5 V, V- = -5 V $V_{IN} = 2.4 V, 0.8 V^{a}$	Temp.b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Offic
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		- 5	5	- 5	5	٧
On-Resistance	R _{ON}	V+ = + 5 V, V- = -5 V $I_S = -10 \text{ mA}, V_D = -3.5 V \text{ to} + 3.5 V$	Room Full	3.8		11 15		11 12	Ω
On-Resistance Match	ΔR _{ON}	V+ = + 5 V, V- = -5 V, $I_S = -10 \text{ mA}, V_D = \pm 3.5 V$	Room Full	0.13		0.5 1		0.5 0.5	22
Dynamic Characteristics	3								
Turn-On Time ^e	t _{ON}	$R_L = 300 \Omega$, $C_L = 35 pF$	Room Full	170		200 296		200 256	
Turn-Off Time ^e	t _{OFF}	$V_S = 3 V$, See Figure 2	Room Full	66		96 124		96 113	ns
Break-Before-Make ^e Time Delay	t _D	DG456 only, $V_S = 3 \text{ V}$ $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$	Room	98					
Charge Injection ^e	Q	$V_g = 0 \text{ V, } R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	8					рC

DG454, DG455, DG456

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SPECIFICATIONS	SPECIFICATIONS FOR DUAL SUPPLIES									
Parameter	Symbol	Test Conditions Unless Specified	- h	Tomp b	_	- 40 °C to 125 °C		- 40 °C to 85 °C		Unit
		V+ = 5 V, V- = -5 V $V_{IN} = 2.4 V, 0.8 V^{a}$	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d		
Power Supplies										
Power Supply Current	l+		Room Full	14		100 100		100 100		
Negative Supply Current	l-	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ	
Ground Current	I _{GND}		Room Full	- 14	- 100 - 100		- 100 - 100			

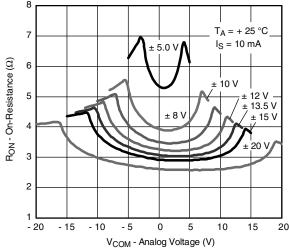
SPECIFICATIONS FOR UNIPOLAR SUPPLIES									
Parameter	Symbol	Test Conditions Unless Specified	T b		- 40 °C to 125 °C		- 40 °C	to 85 °C	Unit
rai ailletei	Symbol	V+ = 12 V, V- = 0 V V _{IN} = 2.4 V, 0.8 V ^a	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Oilit
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full			12		12	V
On-Resistance	R _{ON}	$I_S = -10 \text{ mA}, V_D = 0 \text{ V to} + 10 \text{ V}$	Room Full	5.5		8.1 12.4		8.1 10.4	
On-Resistance Match	ΔR _{ON}	I _S = - 10 mA, V _D = + 10 V	Room Full	0.14		0.5 1		0.5 0.5	Ω
On-Resistance Flatness	R _{FLATNESS}	$I_S = -10 \text{ mA},$ $V_D = 0 \text{ V}, + 5 \text{ V}, + 10 \text{ V}$	Room Full	0.94		1.5 1.7		1.5 1.5	
Dynamic Characteristics									
Turn-On Time	t _{ON}	$R_L = 300 \Omega, C_L = 35 pF$	Room Full	132		162 238		162 210	
Turn-Off Time	t _{OFF}	V _S = 8 V, See Figure 2	Room Full	61		91 117		91 105	ns
Break-Before-Make Time Delay	t _D	DG456 only, $V_S = 8 \text{ V}$ $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$	Room	70					
Charge Injection ^e	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	1					рC
Power Supplies									
Power Supply Current	l+		Room Full	25		100 100		100 100	
Negative Supply Current	I-	V+ = 13.5 V, V- = 0 V V _{IN} = 0 or 5 V	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ
Ground Current	I _{GND}		Room Full	- 25	- 100 - 100		- 100 - 100		

- a. V_{IN} = input voltage to perform proper function.
- b. Room = 25 $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.

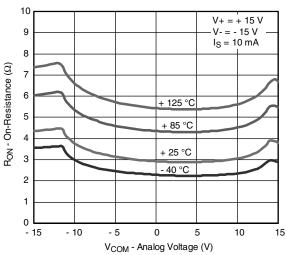
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



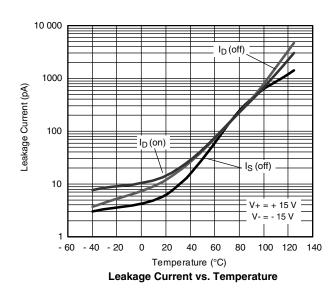
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



On-Resistance vs. $V_{\rm D}$ and Dual Supply Voltage

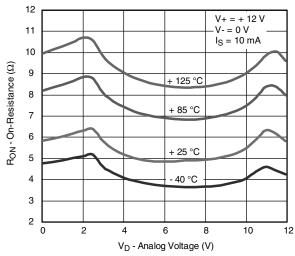


On-Resistance vs. V_D and Temperature

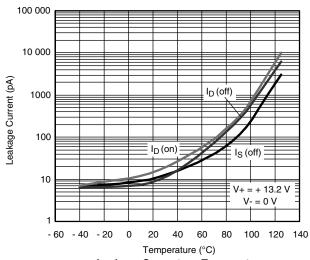


20 T_A = + 25 °C $I_S = 10 \text{ mA}$ 15 R_{ON} - On-Resistance (Ω) V+ = 5 V 10 V+ = 10.8 V + = 15 V 5 V + = 36 V0 12 20 28 V_{COM} - Analog Voltage (V)

On-Resistance vs. V_D and Single Supply Voltage



On-Resistance vs. V_D and Temperature

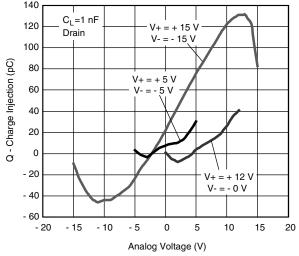


Leakage Current vs. Temperature

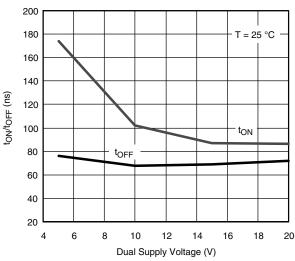
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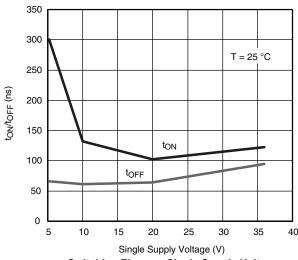
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



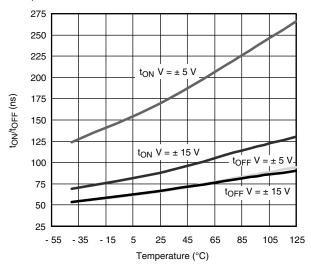
Charge Injection vs. Analog Voltage



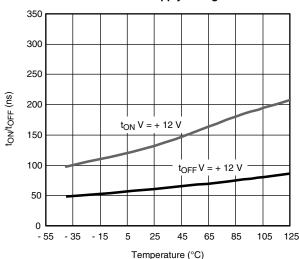
Switching Time vs. Dual Supply Voltage



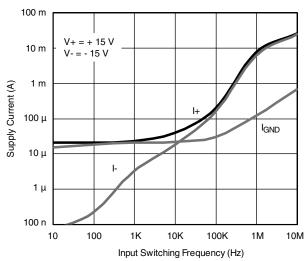
Switching Time vs. Single Supply Voltage



Switching Time vs. Temperature and Dual Supply Voltage



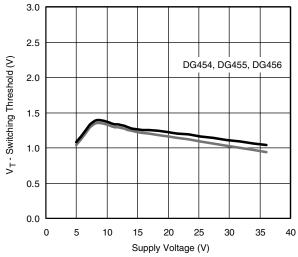
Switching Time vs. Temperature and Single Supply Voltage



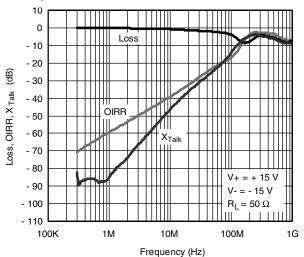
Supply Current vs. Input Switching Frequency



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

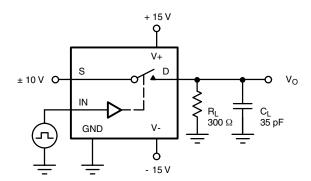


Switching Threshold vs. Supply Voltage



Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

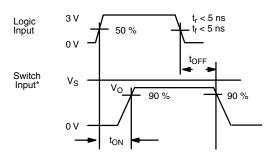
TEST CIRCUITS



C_L (includes fixture and stray capacitance)

$$V_O = V_S$$
 $\frac{R_L}{R_L + R_{DS(on)}}$

C_L (includes fixture and stray capacitance)



Logic input waveform is inverted for switches that Note: have the opposite logic sense control

Figure 1. Switching Time

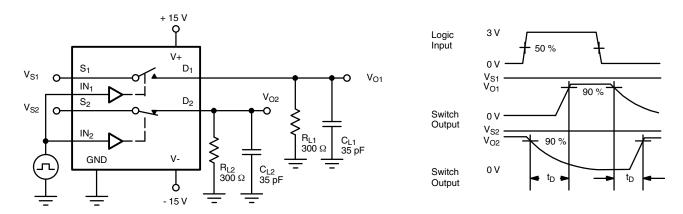


Figure 2. Break-Before-Make (DG456)

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TEST CIRCUITS



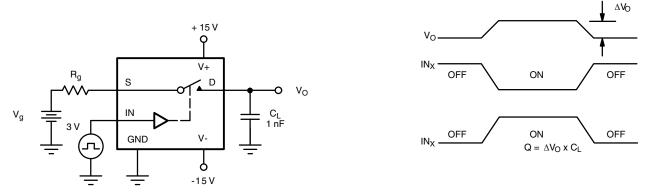


Figure 3. Charge Injection

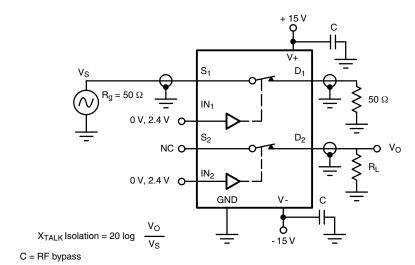
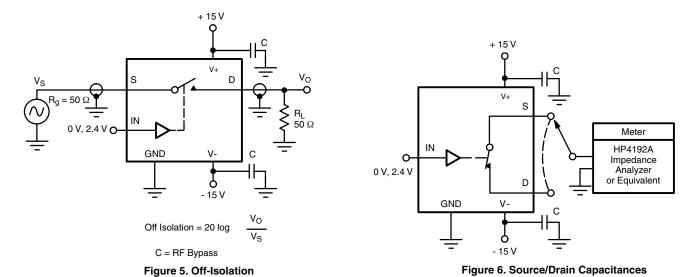


Figure 4. Crosstalk

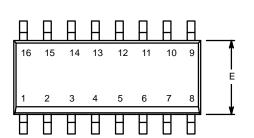


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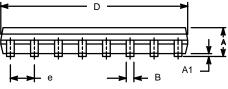
SOIC (NARROW): 16-LEAD JEDEC Part Number: MS-012

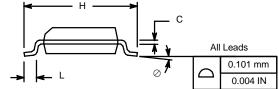


	MILLIMETERS		INC	HES		
Dim	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.38	0.51	0.015	0.020		
С	0.18	0.23	0.007	0.009		
D	9.80	10.00	0.385	0.393		
Е	3.80	4.00	0.149	0.157		
е	1.27	BSC	0.050	BSC		
Н	5.80	6.20	0.228	0.244		
L	0.50	0.93	0.020	0.037		
0	0°	8°	0°	8°		
FCN: S-03946—Rev. F. 09-Jul-01						

ECN: S-03946—Rev. F, 09-Jul-01

DWG: 5300

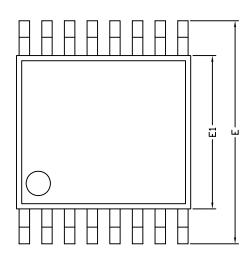


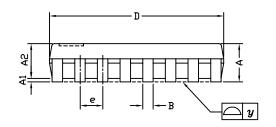


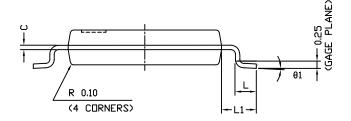
www.vishay.com 02-Jul-01



TSSOP: 16-LEAD







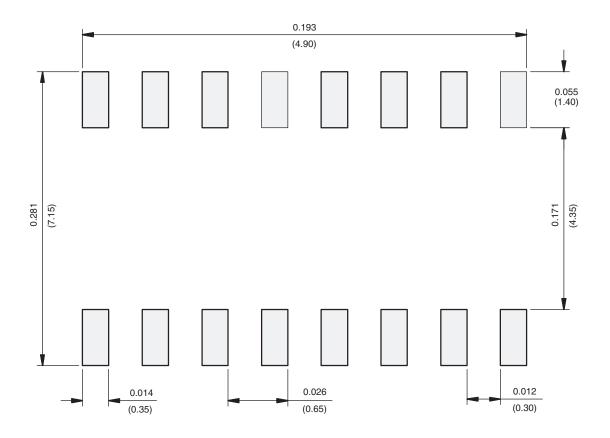
	DIMENSIONS IN MILLIMETERS						
Symbols	Min	Nom	Max				
А	=	1.10	1.20				
A1	0.05	0.10	0.15				
A2	=	1.00	1.05				
В	0.22	0.28	0.38				
С	=	0.127	-				
D	4.90	5.00	5.10				
E	6.10	6.40	6.70				
E1	4.30	4.40	4.50				
е	-	0.65	-				
L	0.50	0.60	0.70				
L1	0.90	1.00	1.10				
у	=	-	0.10				
θ1	0°	3°	6°				
ECN: S-61920-Rev. D. 23-0	Oct-06	<u> </u>					

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



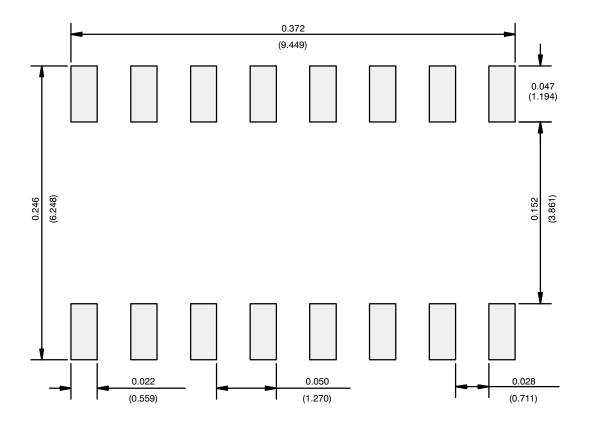
RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads Dimensions in Inches/(mm)

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